

3.3V CMOS 16-BIT IDT74LVCH16245A BUS TRANSCEIVER WITH 3-STATE OUTPUTS, 5 VOLT TOLERANT I/O AND BUS-HOLD

FEATURES:

- Typical tSK(o) (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- Vcc = 3.3V ± 0.3V, Normal Range
- Vcc = 2.7V to 3.6V, Extended Range
- CMOS power levels (0.4µ W typ. static)
- · All inputs, outputs, and I/O are 5V tolerant
- Available in SSSOP and TSSOP packages

DRIVE FEATURES:

- High Output Drivers: ±24mA
- · Reduced system switching noise

APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- · Data communication and telecommunication systems

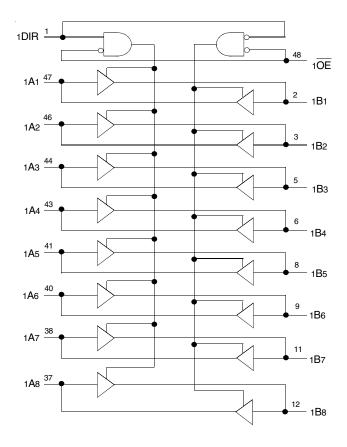
DESCRIPTION:

This 16-bit bus transceiver is built using advanced dual metal CMOS technology. This high-speed, low power transceiver is ideal for asynchronous communication between two busses (A and B). The Direction and Output Enable controls are designed to operate this device as either two independent 8-bit transceivers or one 16-bit transceiver. The direction control pin (DIR) controls the direction of data flow. The output enable pin (\overline{OE}) overrides the direction control and disables both ports. All inputs are designed with hysteresis for improved noise margin.

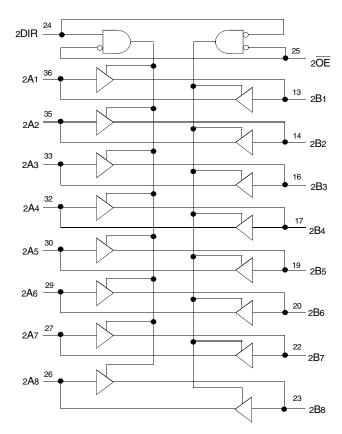
All pins can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V supply system.

The LVCH16245A has been designed with a \pm 24mA output driver. This driver is capable of driving a moderate to heavy load while maintaining speed performance.

The LVCH16245A has "bus-hold" which retains the inputs' last state whenever the input goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.



FUNCTIONAL BLOCK DIAGRAM



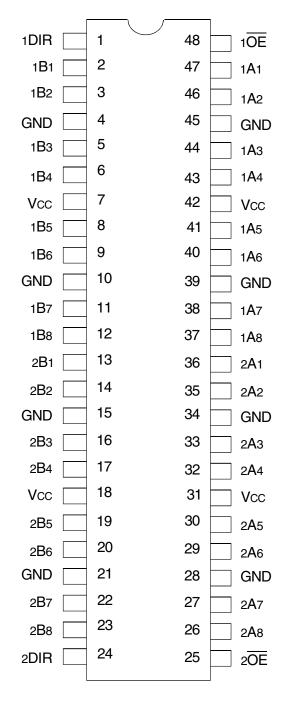
INDUSTRIAL TEMPERATURE RANGE

OCTOBER 2015

IDT74LVCH16245A 3.3V CMOS 16-BIT BUS TRANSCEIVER WITH 3-STATE OUTPUTS

INDUSTRIAL TEMPERATURE RANGE

PIN CONFIGURATION



SSOP/ TSSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM	Terminal Voltage with Respect to GND	–0.5 to +6.5	V
Tstg	Storage Temperature	–65 to +150	°C
Ιουτ	DC Output Current	–50 to +50	mA
Ік Іок	Continuous Clamp Current, Vı < 0 or Vo < 0	-50	mA
lcc Iss	Continuous Current through each Vcc or GND	±100	mA

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (TA = +25°C, F = 1.0MHz)

Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
Input Capacitance	VIN = 0V	4.5	6	pF
Output Capacitance	Vout = 0V	6.5	8	рF
I/O Port Capacitance	VIN = 0V	6.5	8	pF
	Input Capacitance Output Capacitance	Input CapacitanceVIN = 0VOutput CapacitanceVOUT = 0V	Input CapacitanceVIN = 0V4.5Output CapacitanceVOUT = 0V6.5	Input CapacitanceVIN = 0V4.56Output CapacitanceVOUT = 0V6.58

NOTE:

1. As applicable to the device type.

PIN DESCRIPTION

Pin Names	Description	
xŌĒ	Output Enable Inputs (Active LOW)	
xDIR	Direction Control Input	
xAx Side A Inputs or 3-State Outputs ⁽¹⁾		
хВх	x B x Side B Inputs or 3-State Outputs ⁽¹⁾	

NOTE:

1. These pins have "Bus-Hold". All other pins are standard inputs, outputs, or I/Os.

FUNCTION TABLE (EACH 8-BIT SECTION)(1)

Inp	uts		
xOE	xDIR	Outputs	
L	L	Bus B Data to Bus A	
L	Н	Bus A Data to Bus B	
Н	Х	Isolation	

NOTES:

1. H = HIGH Voltage Level

X = Don't Care

L = LOW Voltage Level

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Operating Condition: TA = -40 °C to +85 °C

Symbol	Parameter	Test Co	nditions	Min.	Typ. ⁽¹⁾	Max.	Unit
Vih	Input HIGH Voltage Level	Vcc = 2.3V to 2.7V		1.7	_	_	V
		Vcc = 2.7V to 3.6V		2	-	_	
VIL	Input LOW Voltage Level	Vcc = 2.3V to 2.7V		_	_	0.7	V
		Vcc = 2.7V to 3.6V		_	_	0.8	
Ін	Input Leakage Current	Vcc = 3.6V	VI = 0 to 5.5V		-	±5	μA
lı∟							
lozн	High Impedance Output Current	Vcc = 3.6V	Vo = 0 to 5.5V	-	-	±10	μA
Iozl	(3-State Output pins)						
loff	Input/Output Power Off Leakage	Vcc = 0V, VIN or Vo ≤ 5.5 V		_	-	±50	μA
Vik	Clamp Diode Voltage	Vcc = 2.3V, IIN = -18mA		-	-0.7	-1.2	V
Vн	Input Hysteresis	Vcc = 3.3V		_	100	_	mV
ICCL	Quiescent Power Supply Current	Vcc = 3.6V	VIN = GND or VCC	-	-	10	μA
Іссн Іссz			$3.6 \le VIN \le 5.5V^{(2)}$			10	
Δlcc	Quiescent Power Supply Current Variation	One input at Vcc - 0.6V, other i	nputs at Vcc or GND	-	-	500	μA

NOTES:

1. Typical values are at Vcc = 3.3V, +25°C ambient.

2. This applies in the disabled state only.

BUS-HOLD CHARACTERISTICS

Symbol	Parameter ⁽¹⁾	Test Conditions		Min.	Typ. ⁽²⁾	Max.	Unit
Івнн	Bus-Hold Input Sustain Current	Vcc = 3V	VI = 2V	-75	—	-	μA
IBHL			VI = 0.8V	75	_	—	
Івнн	Bus-Hold Input Sustain Current	Vcc = 2.3V	VI = 1.7V	_	—	_	μA
IBHL			VI = 0.7V	—	_	—	
Івнно	Bus-Hold Input Overdrive Current	Vcc = 3.6V	VI = 0 to 3.6V	—	—	±500	μA
Ibhlo							

NOTES:

1. Pins with Bus-Hold are identified in the pin description.

2. Typical values are at Vcc = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	TestCon	ditions ⁽¹⁾	Min.	Max.	Unit
Vон	Output HIGH Voltage	Vcc = 2.3V to 3.6V	Іон = - 0.1mA	Vcc-0.2	_	V
		Vcc = 2.3V	Iон = - 6mA	2	_	[
		Vcc = 2.3V	Іон = – 12mA	1.7	_	
		Vcc = 2.7V		2.2	_	
		Vcc = 3V	1	2.4	_	
		Vcc = 3V	Iон = - 24mA	2.2	_	
Vol	Output LOW Voltage	Vcc = 2.3V to 3.6V	IoL = 0.1mA	—	0.2	V
		Vcc = 2.3V	IoL = 6mA	—	0.4	
			IoL = 12mA	_	0.7	
		Vcc = 2.7V	IoL = 12mA	_	0.4	
		Vcc = 3V	IoL = 24mA	_	0.55	

NOTE:

1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = − 40°C to + 85°C.

OPERATING CHARACTERISTICS, Vcc = 3.3V ± 0.3V, TA = 25°C

Symbol	Parameter	Test Conditions	Typical	Unit
Cpd	Power Dissipation Capacitance per Transceiver Outputs enabled	CL = 0pF, f = 10Mhz	40	pF
Cpd	Power Dissipation Capacitance per Transceiver Outputs disabled		4	

SWITCHING CHARACTERISTICS⁽¹⁾

		Vcc =	2.7V	Vcc = 3.3	V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
tPLH	Propagation Delay	—	4.7	1	4	ns
t PHL	xAx to xBx, xBx to xAx					
tРZH	Output Enable Time	—	6.7	1.5	5.5	ns
tPZL	xOE to xAx or xBx					
tPHZ	Output Disable Time	—	7.1	1.5	6.6	ns
tPLZ	xOE to xAx or xBx					
tsk(o)	Output Skew ⁽²⁾	—	—	—	1	ns

NOTES:

1. See TEST CIRCUITS AND WAVEFORMS. TA = - 40°C to + 85°C.

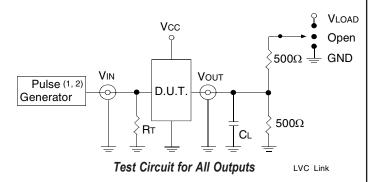
2. Skew between any two outputs of the same package and switching in the same direction.

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INDUSTRIAL TEMPERATURE RANGE

TEST CIRCUITS AND WAVEFORMS TEST CONDITIONS

Symbol	Vcc ⁽¹⁾ =3.3V±0.3V	Vcc ⁽¹⁾ =2.7V	Vcc ⁽²⁾ =2.5V±0.2V	Unit
VLOAD	6	6	2 x Vcc	V
Vih	2.7	2.7	Vcc	V
Vт	1.5	1.5	Vcc/2	V
Vlz	300	300	150	mV
Vнz	300	300	150	mV
CL	50	50	30	pF



DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

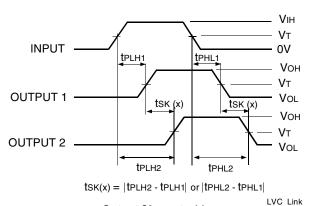
RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

NOTES:

1. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2.5ns; tR \leq 2.5ns. 2. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

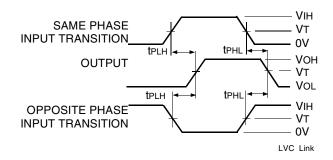
Test	Switch
Open Drain Disable Low Enable Low	VLOAD
Disable High Enable High	GND
All Other Tests	Open



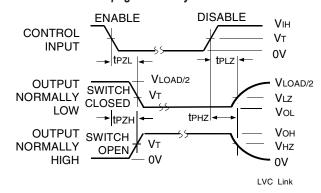
Output Skew - tsk(x)

NOTES:

- 1. For tsk(o) OUTPUT1 and OUTPUT2 are any two outputs.
- 2. For tsk(b) OUTPUT1 and OUTPUT2 are in the same bank.



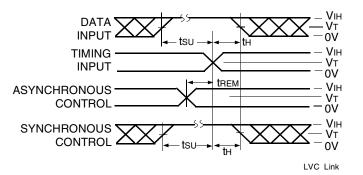
Propagation Delay

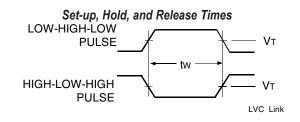


Enable and Disable Times

NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

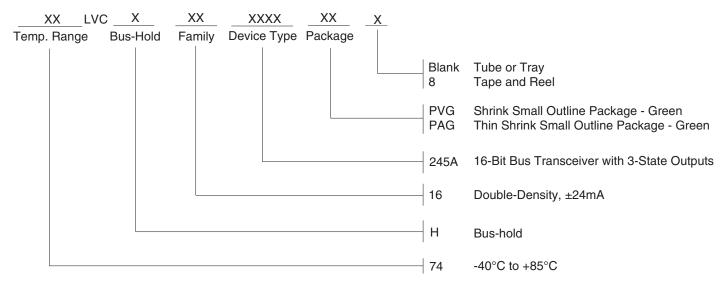




Pulse Width

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ORDERING INFORMATION



DATASHEET DOCUMENT HISTORY

10/06/2015 Pg. 6 Updated the ordering information by removing non RoHS parts and adding Tape and Reel information.

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